NSN 5961-01-049-2667

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-049-2667 **Inclosure Material:** Metal **Overall Length:** 0.090 inches Overall Diameter: Between 0.490 inches and 0.510 inches **Mounting Facility Quantity:** 1 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 85.0 collector to base voltage/static/emitter open and 85.0 collector to emitter voltage/static/base open and 90.0 collector to emitter voltage, dc with base short-circuited to emitter and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 4.50 amperes source cutoff current **Power Rating Per Characteristic:** 70.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 13499-352-0901 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

NSN 5961-01-049-2667 Transistor - Page 2 of 2



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